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TITLE:

Rendering SiO₂/Si Surfaces Omniphobic by Carving Gas-Entrapping Microtextures Comprising Reentrant and Doubly Reentrant Cavities or Pillars

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wetting, omniphobicity, reentrant and doubly reentrant cavities/pillars, gas-entrapping microtextures (GEMs), photolithography, isotropic etching, anisotropic etching, thermal oxide growth, reactive-ion etching, contact angles, immersion, confocal microscopy

SUMMARY:

This work presents microfabrication protocols for achieving cavities and pillars with reentrant and doubly reentrant profiles on SiO₂/Si wafers using photolithography and dry etching. Resulting microtextured surfaces demonstrate remarkable liquid repellence, characterized by robust long-term entrapment of air under wetting liquids, despite the intrinsic wettability of silica.

ABSTRACT:

We present microfabrication protocols for rendering intrinsically wetting materials repellent to liquids (omniphobic) by creating gas-entrapping microtextures (GEMs) on them comprising cavities and pillars with reentrant and doubly reentrant features. Specifically, we use SiO₂/Si as the model system and share protocols for two-dimensional (2D) designing, photolithography, isotropic/anisotropic etching techniques, thermal oxide growth, piranha cleaning, and storage towards achieving those microtextures. Even though the conventional wisdom indicates that roughening intrinsically wetting surfaces ($\theta_0 < 90^\circ$) renders them even more wetting ($\theta < \theta_0 < 90^\circ$) GEMs demonstrate liquid repellence despite the intrinsic wettability of the substrate. For

instance, despite the intrinsic wettability of silica, $\theta_0 \approx 40^\circ$, for the water/air system and $\theta_0 \approx 20^\circ$ for hexadecane/air system, GEMs comprising cavities entrap air robustly on immersion in those liquids, and the apparent contact angles for the droplets are $\theta \approx 90^\circ$. The reentrant and doubly reentrant features in the GEMs stabilize the intruding liquid meniscus thereby trapping the liquid-solid-vapor system in metastable air-filled states (Cassie states) and delaying wetting transitions to the thermodynamically-stable fully-filled state (Wenzel state) by, for instance, hours to months. Similarly, SiO_2/Si surfaces with arrays of reentrant and doubly reentrant micropillars demonstrate extremely high contact angles ($\theta \approx 150^\circ\text{--}160^\circ$) and low contact angle hysteresis for the probe liquids, thus characterized as superomniphobic. However, on immersion in the same liquids, those surfaces dramatically lose their superomniphobicity and get fully-filled within <1 s. To address this challenge, we present protocols for hybrid designs that comprise arrays of doubly reentrant pillars surrounded by walls with doubly reentrant profiles. Indeed, hybrid microtextures entrap air on immersion in the probe liquids. To summarize, the protocols described here should enable the investigation of GEMs in the context of achieving omniphobicity without chemical coatings, such as perfluorocarbons, which might unlock the scope of inexpensive wetting materials for applications as omniphobic materials. Silica microtextures could also serve as templates for soft materials.

INTRODUCTION:

Solid surfaces that exhibit apparent contact angles, $\theta > 90^\circ$ for polar and nonpolar liquids, such as water and hexadecane, are referred to as omniphobic¹. These surfaces serve numerous practical applications, including water desalination^{2,3}, oil-water separation^{4,5}, antibiofouling⁶, and reducing hydrodynamic drag⁷. Typically, omniphobicity necessitates perfluorinated chemicals and random topographies^{8–12}. However, the cost, non-biodegradability, and vulnerability of those materials/coatings pose a myriad of constraints, e.g., perfluorinated desalination membranes degrade as the feed-side temperatures are raised, leading to pore-wetting^{13,14}, and perfluorinated/hydrocarbon coatings also get abraded^{15,16} and degraded by silt particles in the flow streams and cleaning protocols. Thus, there is a need for alternative strategies for achieving the functions of perfluorinated coatings (i.e., entrapping air on immersion in liquids without using water repellent coatings). Therefore, researchers have proposed surface topographies comprised of overhanging (reentrant) features that could entrap air on immersion by microtexturing alone^{17–25}. These microtextures come in three types: cavities²⁶, pillars²⁷, and fibrous mats⁸. Hereafter, we will refer to reentrant features with simple overhangs as reentrant (**Figure 1A–B** and **Figure 1E–F**) and reentrant features with overhangs that make a 90° -turn towards the base as doubly reentrant **Figure 1C–D** and **Figure 1G–H**).

In their pioneering work, Werner et al.^{22,28–31} characterized cuticles of springtails (Collembola), soil-dwelling arthropods, and explained the significance of mushroom-shaped (reentrant) features in the context of wetting. Others have also investigated the role of mushroom-shaped hairs in sea-skaters^{32,33} towards facilitating extreme water repellence. Werner and coworkers demonstrated the omniphobicity of intrinsically wetting polymeric surfaces by carving biomimetic structures through reverse imprint lithography²⁹. Liu and Kim reported on silica surfaces adorned with arrays of doubly reentrant pillars that could repel drops of liquids with surface tensions as low as $\gamma_{LV} = 10$ mN/m, characterized by apparent contact angles, $\theta \approx 150^\circ$ and

extremely low contact angle hysteresis²⁷. Inspired by these amazing developments, we followed the recipes of Liu and Kim to reproduce their results. However, we discovered that those microtextures would catastrophically lose their superomniphobicity, i.e. $\theta_t \rightarrow 0^\circ$, if wetting liquid drops touched the edge of the microtexture or if there was localized physical damage³⁴. These findings demonstrated that pillar-based microtextures were unfit for applications that required omniphobicity on immersion, and they also questioned the criteria for assessing omniphobicity (i.e., should they be limited to contact angles alone, or if additional criteria are needed).

In response, using the SiO₂/Si wafers, we prepared arrays of microscale cavities with doubly reentrant inlets and, and using water and hexadecane as the representative polar and nonpolar liquids, we demonstrated that (i) these microtextures prevent liquids from entering them by entrapping air, and (ii) the compartmentalized architecture of the cavities prevents the loss of entrapped air by localized defects³⁴. Thus, we describe them as gas-entrapping microtextures (GEMs). As the next step, we microfabricated a variety of shapes (circular, square, hexagonal) and profiles (simple, reentrant, and doubly reentrant) to systematically compare their performance under immersion in wetting liquids²⁶. We also created a hybrid microtexture comprising arrays of doubly reentrant pillars surrounded by walls with doubly reentrant profiles, which prevented liquids from touching the stems of the pillars and robustly entrapped air on immersion³⁵. Below, we present detailed protocols for manufacturing GEMs through photolithography and etching techniques along with design parameters. We also present representative results of characterizing their wetting by contact angle goniometry (advancing/receding/as-placed angles) and immersion in hexadecane and water.

PROTOCOLS:

NOTE: Arrays of reentrant and doubly reentrant cavities and pillars were microfabricated by adapting the multistep protocol for pillars reported by Liu and Kim²⁷. Precautions were taken to minimize the formation of pin residues or particles on our surfaces that could interfere with wetting transitions³⁶.

MICROFABRICATION OF CAVITIES

Broadly, the protocols for the microfabrication of reentrant and doubly reentrant cavities (RCs and DRCs) consist of two-dimensional layout designing, photolithography, general silica etching, and specific silicon etching, depending on the final feature required^{37–41}.

1. Design

1.1. Start the microfabrication process by designing the required pattern in a layout software⁴². An example of such a software is listed in the **Materials List**.

1.2. Using the software, create a new file. Draw a unit cell comprising a circle of diameter, $D = 200 \mu\text{m}$. Copy and paste this circle with a center-to-center distance (pitch) of $L = 212 \mu\text{m}$ to create an array of circles in a square patch of area 1 cm^2 (**Figure 1**).

1.3. Draw a circle of diameter 100 mm (4 inches). Place the 1 cm² square array inside the circle and replicate it to create a 4 x 4 grid of square arrays. Features inside the circle will be transferred onto the 4-inch wafers (**Figure 2**).

1.4. Export the design file to the desired format for the mask writing system (e.g., the GDSII format).

2. Cleaning of wafers

2.1. Clean a silicon wafer 4 inches in diameter, <100> orientation, and with a 2.4 μm thick thermal oxide layer (see the **Materials List**), in piranha solution for 10 min. Piranha solution comprises sulfuric acid (H₂SO₄, 96%): hydrogen peroxide (H₂O₂, 30%) in a 3:1 volumetric ratio and is maintained at $T = 388$ K.

2.2. Rinse the wafer with deionized water and spin-dry under nitrogen (N₂) environment.

3. Photolithography

3.1 Coat the wafer with hexamethyldisilazane (HMDS) using vapor-phase deposition to improve adhesion with the photoresist. Refer to **Table 1** for the process details.

3.2. Mount the wafer on a 4-inch vacuum chuck in the spin coater. Cover the wafer with the AZ-5214E photoresist. Use the spin coater to spread the photoresist uniformly on the surface as a 1.6 μm-thick layer. Refer to **Table 2** for spin coating parameters.

3.3. Bake the photoresist-coated wafer on a hot-plate maintained at 110 °C for 120 s.

3.4. Transfer the wafer to a direct-writing system and expose the wafer to UV radiation for 55 ms (defocus: +5). This step transfers the desired design on the AZ-5214E (used in the positive tone; see **Materials List**) (**Figure 2**).

3.5. Place the UV-exposed wafer in a glass Petri dish containing the AZ-726 developer for 60 s for the features to develop. See **Materials List** for details.

3.6. Remove the wafer from the developer solution and rinse with deionized (DI) water gently to remove excess developer. Spin dry the wafer in a N₂ environment. These steps are presented in **Figure 3A–C**.

NOTE: At the end of this step, design patterns on the wafer can be seen under a standard optical microscope.

4. Anisotropic etching of silica (SiO₂) layer

NOTE: The goal of this step is to completely etch away the silica layer (2.4 μm-thick) that was

exposed during photolithography to expose the silicon layer underneath.

4.1. After photolithography, transfer the wafer to an inductively coupled plasma (ICP) reactive-ion etching (RIE) system that employs a mixture of octafluorocyclobutane (C_4F_8) and oxygen (O_2) gases to etch silica vertically downward (anisotropic etching).

4.2. Run the ICP-RIE process for approximately 13 min to etch the exposed silica layer. Refer to the ICP-RIE parameters in **Table 3**. During this step, the photoresist layer also gets completely etched away (**Figure 3C–D**).

4.3. To ensure that the silica layer thickness inside the desired patterns is reduced to zero, so that the silicon layer is exposed, measure the thickness of the remaining silica using a reflectometer. Adjust the duration of the subsequent etching period based on the thicknesses of the silica layers (especially in and around the patterns).

NOTE: A reflectometer was used to measure the thickness of the remaining silica layer⁴³. Alternatively, other tools, such as ellipsometer or an interactive color chart to predict the color of SiO_2 and thickness can also be used^{44,45}.

The procedures detailed in steps 1 and 4 are common for both reentrant and doubly reentrant cavities. However, the etching protocols for the silicon layer are different and are described below:

5. Reentrant cavities

5.1. Anisotropic silicon etching

5.1.1. After etching the silica layer, transfer the wafer to a deep ICP-RIE system to etch silicon. The first step consists of a fluorine-based anisotropic etching method known as the Bosch process that etches silicon vertically downward, creating a straight wall.

NOTE: The Bosch process uses C_4F_8 and sulfur hexafluoride (SF_6) gases in the reaction chamber: the C_4F_8 deposition creates a passivation layer, while the SF_6 etches silicon vertically downward. Thus, the Bosch process enables the microfabrication of deep trenches in silicon with high-aspect ratios.

5.1.2. Run this process for five cycles, which corresponds to an etching depth for silicon equivalent to $\approx 2 \mu m$. Process parameters are listed in **Table 4**.

5.1.3. Clean the wafer in piranha solution for 10 min to remove any remnants of the Bosch process. Rinse the wafer with DI water and spin-dry in a N_2 environment (**Figure 3E**).

5.2. Isotropic silicon etching: In order to create the reentrant feature, perform isotropic etching that would create an undercut beneath the silica layer. A $5 \mu m$ overhang can be achieved by

etching the silicon layer with SF_6 for 2 min 45 s (**Figure 3F**). Refer to **Table 5** for the process parameters.

5.3. Anisotropic silicon etching: Once the reentrant features are created, tune the depth of the cavities by the Bosch process (step 5.1).

NOTE: To microfabricate cavities with a depth of $h_c \approx 50 \mu\text{m}$, 160 cycles of the Bosch process are required (**Figure 3G**, **Table 4**).

5.4. Wafer cleaning and storage

5.4.1. Clean the wafer using piranha solution as described in step 2. After this step, the wafer becomes superhydrophilic, characterized by contact angles of water, $\theta_0 \approx 0^\circ$.

5.4.2. Store the wafer in a glass Petri dish and place inside a clean vacuum oven maintained at $T = 323 \text{ K}$ and vacuum pressure $P_{\text{vac}} = 3.3 \text{ kPa}$ for 48 h, after which the intrinsic contact angle of the silica layer stabilizes to $\theta_0 \approx 40^\circ$.

5.4.3. Store the samples in a clean cabinet equipped with an outward nitrogen (99%) flow, ready for further characterization.

6. Doubly reentrant cavities

6.1. Anisotropic silicon etching: To create doubly reentrant cavities, follow steps 1, 2, 3, 4, and 5.1 (see **Figures 4A-E**).

6.2. Isotropic silicon etching

In order to create doubly reentrant features, reentrant features must be created first. To achieve that, perform isotropic etching to create an undercut beneath the silica layer. Etch the silicon layer with SF_6 for 25 s (**Figure 4F**). Refer to **Table 5** for the process parameters. Subsequently, clean the wafer using piranha solution as described in step 2.

6.3. Thermal oxide growth

6.3.1. To achieve doubly reentrant features, grow a 500 nm layer of thermal oxide on the wafer, using a high temperature furnace system (**Figure 4G**).

6.3.2. Measure the thickness of the oxide layer using a reflectometer.

NOTE: The oxidation was carried out by exposing the samples to an environment comprising oxygen (O_2) and water vapor, leading to the wet oxidation of silicon in an enclosed environment at temperatures ranging from 800–1,200 °C.

6.4. Silica etching: Carry out the same process as described in the step 4 to etch silica vertically downward for 3 min. As a result of the anisotropic etching, the thermal oxide (500 nm thick silica layer) is etched away from the cavity, but it leaves an “overhang” along the sidewalls that would form the doubly reentrant edge eventually (**Figure 4H, Table 3**).

6.5. Anisotropic silicon etching: Repeat five cycles of the Bosch process to deepen of the cavities by $\approx 2\ \mu\text{m}$ (**Figure 4I, Table 5**). This step is necessary to remove the silicon behind the doubly reentrant feature in the next step. Clean the wafer using piranha solution.

6.6. Isotropic silicon etching: Perform the isotropic etching of silicon for 2 min and 30 s using the process parameters described in **Table 4**. This step creates an empty space ($\approx 2\ \mu\text{m}$) behind the thermally-grown oxide at the mouth of the cavity, leading to the doubly reentrant edge (**Figure 4J**).

6.7. Anisotropic silicon etching: Use the Bosch process recipe (step 5.1) for 160 cycles to increase the depth of the cavities to $h_c \approx 50\ \mu\text{m}$, (**Figure 4K, Table 5**).

6.8. Wafer cleaning and storage: Clean the wafer using piranha solution and store as described in step 5.4 above.

MICROFABRICATION OF PILLARS

The design protocol for fabricating reentrant and doubly reentrant pillars and “hybrids” (comprising doubly reentrant pillars surrounded by walls) consists of three key steps: wafer preparation, silica etching, and specific silicon etching. **Figures 5A–C** show the top-view of the layout design for reentrant and doubly reentrant pillars, while **Figures 5D–F** represent the layout of the hybrid arrays. Select the dark-field option of the UV exposure in order to expose the whole wafer except for the pattern using the same photoresist (AZ5214E) (**Figures 6A–C** and **Figures 7A–C**). Besides these specificities, the processes for cleaning the wafer (step 2) and etching silica (step 4) are identical.

7. Reentrant pillars

7.1. Anisotropic silicon etching: After photolithography, UV exposure, development, and etching silica with the specificities for pillars described above (steps 1–4), transfer the wafer to a deep ICP-RIE system to etch the silicon layer using the Bosch process. This step controls the height of the pillars. Use 160 cycles of the Bosch process to achieve pillars of height, $h_p \approx 30\ \mu\text{m}$ (**Figure 6E, Table 5**). Clean the wafer as described in step 2.

7.2. Isotropic silicon etching: Perform isotropic etching using SF_6 for 5 min to create the reentrant edge on the pillars (**Figure 6F, Table 4**). The resulting length of the overhang is $5\ \mu\text{m}$.

7.3. Piranha cleaning and storage: Clean the wafer using piranha solution and store as described in step 5.4 above.

8. DOUBLY REENTRANT PILLARS AND HYBRIDS

8.1. Anisotropic silicon etching: After etching SiO₂, transfer the wafer to a deep ICP-RIE system to etch the Si under the SiO₂ layer. Perform five cycles of the Bosch process that corresponds to an etching depth of $\approx 2\ \mu\text{m}$ (**Figure 7E**, **Table 4**). Subsequently, clean the wafer as described in step (2).

8.2. Isotropic silicon etching: Carry out isotropic etching using SF₆ for 16 s to create the reentrant edge (**Table 5**, **Figure 7F**). Clean the wafer as described in step 2.

8.3. Thermal oxide growth: Grow 500 nm layer of thermal oxide all over the wafer using a high temperature furnace system as described in step 6.3 (**Figure 7G**).

8.4. Silica etching: Etch the thermally-grown oxide layer (500 nm thick) for 3 min as described in step 6.4 (**Figure 7H**, **Table 3**).

8.5. Anisotropic silicon etching: Repeat 160 cycles of the Bosch process (**Table 4**) to increase the height of the pillars (**Figure 7I**). Clean the wafer as described in step 2 above.

8.6. Isotropic silicon etching: Perform isotropic etching of silicon for 5 min using the process parameters as described in **Table 4**. This step creates the doubly reentrant edge (**Figure 7J**). The space between pillar stem and doubly reentrant edge is $\approx 2\ \mu\text{m}$.

8.7. Wafer cleaning and storage: Clean the wafer using piranha solution and store as described in step 5.4 above.

Figure 8 represents the list of processes used in microfabricating reentrant and doubly reentrant cavities and pillars.

REPRESENTATIVE RESULTS:

In this section, we showcase reentrant and doubly reentrant cavities (RCs and DRCs, **Figure 9**) and reentrant and doubly reentrant pillars (RPs and DRPs, **Figure 10**) microfabricated using the protocols described above. All the cavities have the diameter, $D_C = 200\ \mu\text{m}$, the depth, $h_C \approx 50\ \mu\text{m}$, and the center-to-center distance (or the pitch) between adjacent cavities to be $L_C = D_C + 12\ \mu\text{m}$. Using the same fabrication protocols, cavities of non-circular shapes can also be prepared, as reported previously²⁶.

The diameter of the cap on top of the pillars was $D_P = 20\ \mu\text{m}$, and their height and pitch were, respectively, $h_P \approx 30\ \mu\text{m}$ and $L_P = 100\ \mu\text{m}$ (**Figure 10**).

Wetting Behaviors of Gas-Entrapping Microtextures (GEMs)

Flat silica (SiO₂) is intrinsically wetting towards most polar and nonpolar liquids. For instance, the intrinsic contact angles of droplets of hexadecane ($\gamma_{LV} = 20\ \text{mN/m}$ at 20°C) and water (surface tension $\gamma_{LV} = 72.8\ \text{mN/m}$ at 20 °C) on silica were, respectively, and $\theta_o \approx 20^\circ$ and $\theta_o \approx 40^\circ$. However,

after microfabricating reentrant and doubly reentrant cavities (DRCs) and pillars, the contact angles changed dramatically (**Table 6**). We measured the advancing/receding contact angles by dispensing/retracting the liquids at the rate of 0.2 $\mu\text{L/s}$ and found the apparent contact angles for both liquids, $\theta_r > 120^\circ$, (omniphobic, **Figure 11E**). Receding contact angles, $\theta_r \approx 0^\circ$ because of the lack of discontinuity in the microtextures, such as in pillar-based microtextures. On the other hand, SiO_2/Si surfaces with arrays of doubly reentrant pillars (DRPs) exhibited apparent contact angles, $\theta_r > 150^\circ$ for both liquids and the contact angle hysteresis was minimal (superomniphobic, **Figure 11A** and Movies S1 and S2). Curiously, when the same SiO_2/Si surfaces with arrays of pillars were immersed in the same liquids they got intruded instantaneously, $t < 1$ s, i.e. no air was entrapped (**Figure 10A–D**, Movie S3). So, while the pillars appeared to be superomniphobic in terms of contact angles, they failed to entrap air on immersion. In fact, wetting liquids intrude from the boundary of the microtexture (or from localized defects) and displace any trapped air instantaneously (**Figures 11A–D** and Movie S3). In contrast, DRCs entrapped air upon immersion in both liquids (**Figures 11E–H** and S1, **Table 1**); for hexadecane, the entrapped air was intact even after 1 month²⁶. Our confocal microscopy experiments demonstrated that the overhanging features stabilize the intruding liquids and entrap air inside them (**Figures 12A–B**).

Next, to entrap air in arrays of DRPs, we employed the same microfabrication protocols to achieve arrays of pillars surrounded by walls of doubly reentrant profile (**Figure 10G–I**). This strategy insulated the stems of the DRPs from wetting liquids. As a result, the hybrid microtextures behaved as GEMs, as confirmed by confocal microscopy (**Figure 12C–D**) and Movie S4, **Table 6**). Thus, silica surfaces with hybrid microtextures exhibited omniphobicity on immersion by trapping air and demonstrated contact angles, $\theta_r > 120^\circ$, (omniphobic), and proved omniphobic in the true sense, i.e. in terms of contact angles and entrapping air on immersion. In **Table 6**, we assess the omniphobicity of SiO_2/Si surfaces with a variety of microtextures cavity-based, pillar-based, and hybrids by contact angles and immersion.

FIGURE AND TABLE LEGENDS:

Figure 1. Schematics of microstructures. (A–B) Reentrant cavities, (C–D) doubly reentrant cavities, (E–F) reentrant pillars, (G–H) doubly reentrant pillars.

Figure 2. Design patterns for cavities. Design patterns for reentrant and doubly reentrant cavities generated using the layout software. The pattern was transferred onto the wafer using photolithography.

Figure 3. Microfabrication protocol for reentrant cavities. (A) Clean silicon wafer with 2.4 μm thick silica on top. (B) Spin-coat the wafer with photoresist and expose to UV light. (C) Develop the UV exposed photoresist to obtain the design pattern. (D) Etching of the exposed top silica layer vertically downward (anisotropic etching) using inductively coupled plasma (ICP) reactive-ion etching (RIE). (E) Shallow anisotropic etching of exposed silicon layer using deep ICP-RIE. (F) Isotropic etching of silicon to create the reentrant edge. (G) Deep anisotropic silicon etching to increase the depth of the cavities.

Figure 4. Microfabrication protocol for doubly reentrant cavities. (A) Clean silicon wafer with

2.4 μm thick silica on top. (B) Spin-coat the wafer with photoresist and expose to UV light. (C) Develop the UV exposed photoresist to obtain the design pattern. (D) Etching of the exposed top silica layer vertically downward (anisotropic etching) using inductively coupled plasma (ICP) reactive-ion etching (RIE). (E) Shallow anisotropic etching of exposed silicon layer using deep ICP-RIE. (F) Shallow isotropic etching of silicon to create undercut using deep ICP-RIE. (G) Thermal oxide growth. (H) Anisotropic etching of top and bottom silica layer. (I) Shallow anisotropic etching of silicon. (J) Isotropic silicon etch to create the doubly reentrant edge. (K) Deep anisotropic silicon etching to increase the depth of the cavities.

Figure 5. Design patterns for pillars. Design patterns for reentrant, doubly reentrant, and hybrid pillars generated using the layout software. The pattern was transferred onto the wafer using photolithography.

Figure 6. Microfabrication protocol for reentrant pillars. (A) Clean silicon wafer with 2.4 μm thick silica on top. (B) Spin-coat the wafer with photoresist and expose to UV light. (C) Develop the UV exposed photoresist to obtain the design pattern. (D) Etching of the exposed top silica layer vertically downward (anisotropic etching) using inductively coupled plasma (ICP) reactive-ion etching (RIE). (E) Deep anisotropic silicon etching to increase the height of the pillars. (F) Isotropic silicon etching to create the reentrant edge.

Figure 7. Microfabrication protocol for doubly reentrant pillars. (A) Clean silicon wafer with 2.4 μm thick silica on top. (B) Spin-coat the wafer with photoresist and expose to UV light. (C) Develop the UV exposed photoresist to obtain the design pattern. (D) Etching of the exposed top silica layer vertically downward (anisotropic etching) using inductively coupled plasma (ICP) reactive-ion etching (RIE). (E) Shallow anisotropic etching of exposed silicon layer using deep ICP-RIE. (F) Shallow isotropic etching of silicon to create undercut using deep ICP-RIE. (G) Thermal oxide growth. (H) Anisotropic etching of the top and bottom of silica layer. (I) Anisotropic silicon etching to increase the height of the pillars. (J) Isotropic silicon etching to create the doubly reentrant edge. Note that the only difference between doubly reentrant pillars and the “hybrid” is the design at the beginning.

Figure 8. Microfabrication protocol for reentrant and doubly reentrant cavities and pillars. The flowchart lists the key steps involved.

Figure 9. Scanning electron micrographs of reentrant and doubly reentrant cavities. (A–D) Cross sectional and isometric views of silica surfaces with array of reentrant cavities. (E–H) Cross sectional and top views of doubly reentrant cavities. D_C = diameter of the cavity and L_C = the center-to-center distance between adjacent cavities (or pitch), and h_C = depth of the cavity.

Figure 10. Scanning electron micrographs of reentrant and doubly reentrant pillars. (A–C) Isometric view of reentrant pillars. (D–F) Doubly reentrant pillars. (G–I) Hybrid pillars - DRPs surrounded by doubly reentrant walls. D_P - diameter of the pillar cap and L_P - the center-to-center distance between adjacent pillars (or pitch), and h_P – height of the pillars. **Figures D–I**, reprinted from Ref. ³⁵, Copyright (2019), with permission from Elsevier.

Figure 11. Wetting behavior. (A) Superomniphobicity of SiO₂/Si surfaces adorned with arrays doubly reentrant pillars, observed by placing liquid drops on top. (B–D) The superomniphobicity is lost instantaneously, if wetting liquids touch the boundary or localized defects. (E) SiO₂/Si surfaces adorned with arrays doubly reentrant cavities exhibit omniphobicity. (F–H) These microtextures entrap air robustly and do not lose it if liquid touches the boundary or localized defects. Reprinted from Ref.³⁵, Copyright (2019), with permission from Elsevier.

Figure 12. Confocal microscopy of microtextures immersed in liquids. Computer-enhanced 3D reconstructions of representative confocal images (isometric and cross-sections along the dotted lines) of wetting transitions in silica surfaces with doubly reentrant cavities and hybrid pillars immersed under a $z \approx 5$ mm column after 5 min of immersion of (A,C) water, and (B,D) hexadecane. The (false) blue and yellow colors correspond to the interfaces of water and hexadecane with the trapped air. Intruding liquid menisci were stabilized at doubly reentrant edge. (Scale bar = Diameter of the cavity and pillar 200 μ m and 20 μ m respectively). Figure 12 was reprinted from Ref.³⁵, Copyright (2019), with permission from Elsevier.

Table 1. Process details for coating hexamethyldisilazane (HMDS) layers to enhance the adhesion between the silica surface and the AZ-5214E photoresist.

Table 2. Process details for achieving 1.6 μ m-thick AZ-5214E photoresist layer on SiO₂/Si wafers by spin-coating.

Table 3. Parameter settings for silica etching used in Inductively Coupled Plasma – Reactive Ion Etching (ICP-RIE).

Table 4. Parameter settings for silicon etching (isotropic) used in inductively coupled plasma – deep reactive ion etching (ICP-DRIE).

Table 5. Parameter settings for silicon etching (anisotropic) used in inductively coupled plasma – deep reactive ion etching (ICP-DRIE).

Table 6. Contact angle measurements – advancing (θ_A), receding (θ_R), and apparent (θ_r) —and immersion in liquids. This table reprinted from Ref.³⁵, Copyright (2019), with permission from Elsevier.

Movie S1. High speed image sequence (15K fps) of water droplet bouncing from microtextured surfaces comprising of doubly reentrant pillars. This movie was reprinted from ref 35. Copyright (2019), with permission from Elsevier.

Movie S2. High speed image sequence (19K fps) of hexadecane droplet bouncing from microtextured surfaces comprising of doubly reentrant pillars. This movie was reprinted from ref 35. Copyright (2019), with permission from Elsevier.

Movie S3. Image sequence (200 fps) of water imbibition into microtexture comprising of doubly reentrant pillars. This movie was reprinted from ref 35. Copyright (2019), with permission from Elsevier.

Movie S4. Image sequence (200 fps) water drop advancing next to hybrid microtexture. Presence of doubly reentrant boundary wall prevents liquid invasion into the microtexture, which makes the surface omniphobic under immersion also. This movie was reprinted from ref 35. Copyright (2019), with permission from Elsevier.

DISCUSSION:

Here we discuss additional factors and design criteria to help the reader in applying these microfabrication protocols. For cavity microtextures (RCs and DRCs) the choice of pitch is crucial. On one hand, the thinner the walls between adjacent cavities, the entrapment of air would ensure that the liquid-solid interfacial area is low and the liquid-solid interfacial area is high, leading to high contact angles³⁴. But, if the wall-thickness is too thin, it might compromise the mechanical integrity of the microtexture, for instance, during handling and characterization. Further, if the walls are too thin, then during the isotropic etching towards DRCs (e.g., step 6.6), a little over-etching would destroy the wall, and under-etching would yield doubly reentrant features that are too close to the wall. In the latter scenario, the ability of DRCs to entrap air for long-term might suffer, especially if the liquid would condense inside the cavities²⁶. For this reason, we chose the pitch in our experiments to be $L = D + 12 \mu\text{m}$ (i.e., the minimum wall thickness between the cavities was $12 \mu\text{m}$). We also fabricated doubly reentrant cavities with a smaller pitch of $L = D + 5 \mu\text{m}$, but the resulting surfaces were not homogeneous due to structural damage during microfabrication.

During the etching of the silica layer with C_4F_8 and O_2 in step 4, the prior history of usage or the cleanliness of the reaction chamber could give variable results, despite following the same steps, for instance, in a common user facility such as in most universities. Thus, it is recommended that this step is performed in short time periods, for instance, no more than 5 min each and monitored the thickness of the silica layer by an independent technique, such as reflectometry. For our wafers with a $2.4 \mu\text{m}$ -thick silica layer, a typical etching routine took 13 min to remove silica completely from the targeted areas. Because the photoresist was also etched during the process, this step removed $1 \mu\text{m}$ of the silica layer that was initially masked by the photoresist. Furthermore, to ensure that the etching rate was as expected, and to avoid cross-contamination from previous etch processes (a common issue in multiuser facilities), silica etching was always preceded by etching a sacrificial wafer as a precautionary step. During the development of the photoresist, the exposed surface might get contaminated with the photoresist's traces/particles, which could act as (microscopic) masks leading to the formation of pin residues. To avoid this, rigorous cleaning and storage protocols should be followed throughout the microfabrication process³⁶.

Similarly, during the Bosch process, even though the SiO_2 layer acts as a mask for the Si-layer underneath, it does get etched during long etching cycles, albeit at slower rates. Thus, the depth of the cavities or the height of the pillars is limited up the point that the reentrant features will

not be compromised. The passivation and etching times during the Bosch method should be tuned carefully to obtain smooth walls. This can be achieved by testing iteratively changing recipes and observing their effects on samples, for instance, using electron microscopy.

In the case of RPs and DRPs, the longer the duration of isotropic etching, the smaller the diameter of the stem. If the diameter is less than 10 μm , it might cause instability or fragility. This limitation should inform the design at the beginning of the microfabrication procedure.

Dry-etching tools commonly available in universities do not have industrial-grade tolerances, leading to spatial non-uniformities in terms of the rate of etching inside the chamber. Thus, the features obtained in the center of the wafer might not be the same as those at the boundary. To overcome this limitation, we used four-inch wafers and concentrated only in the central region.

We also recommend using direct-writing systems instead of using hard-contact masks for photolithography, allowing for quickly varying design parameters, diameters, pitches, shapes (circular, hexagonal and square), and overall designs (cavities, pillars, and hybrid designs).

Obviously, neither SiO_2/Si wafers nor photolithography are the desired materials or processes for the mass production of omniphobic surfaces. However, they serve as an excellent model system to explore innovative microtextures for engineering omniphobic surfaces, for instance by biomimetics^{26,27,34,35,46,47}, which can be translated to low-cost and scalable materials systems for applications. It is expected that in the near future, the design principles for GEMs might be scaled up using techniques such as two photon lithography⁴⁸, additive manufacturing⁴⁹, laser micromachining⁵⁰. Microtextured SiO_2/Si surfaces could also be used for templating soft materials^{29,51}. Currently, we are investigating applications of our gas-entrapping surfaces for mitigating cavitation damage⁴⁷, desalination⁴⁶, and reducing hydrodynamic drag.

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DISCLOSURES:

The authors declare that they have no competing interests.

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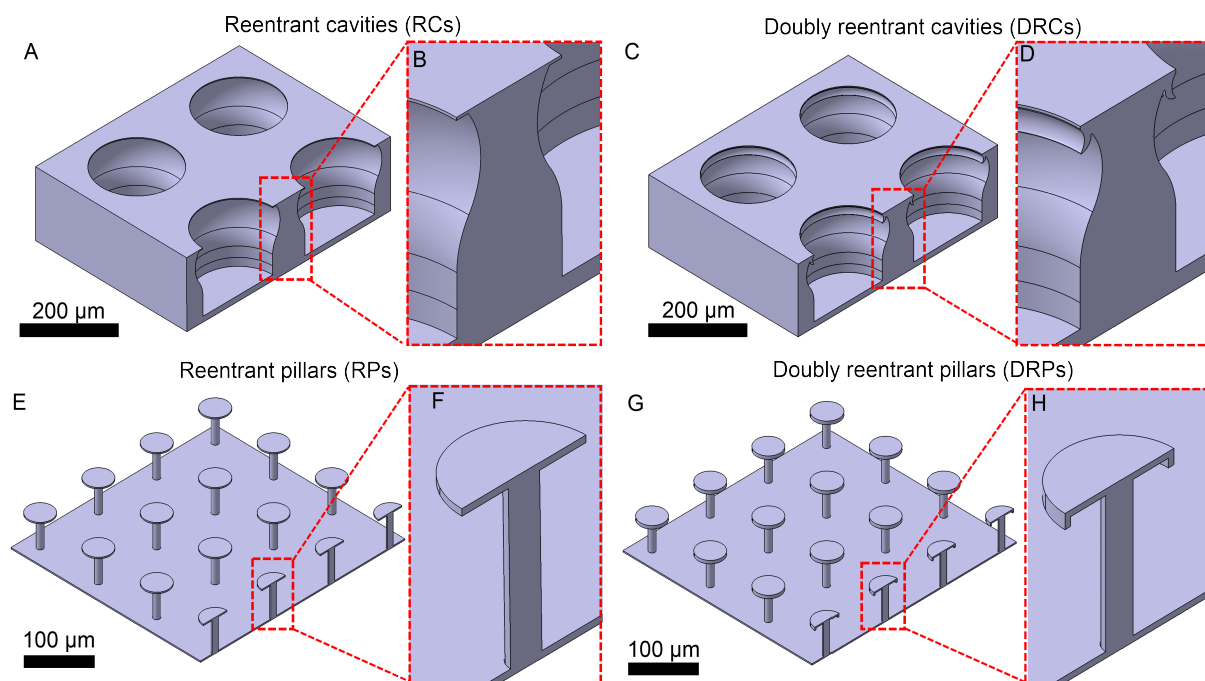
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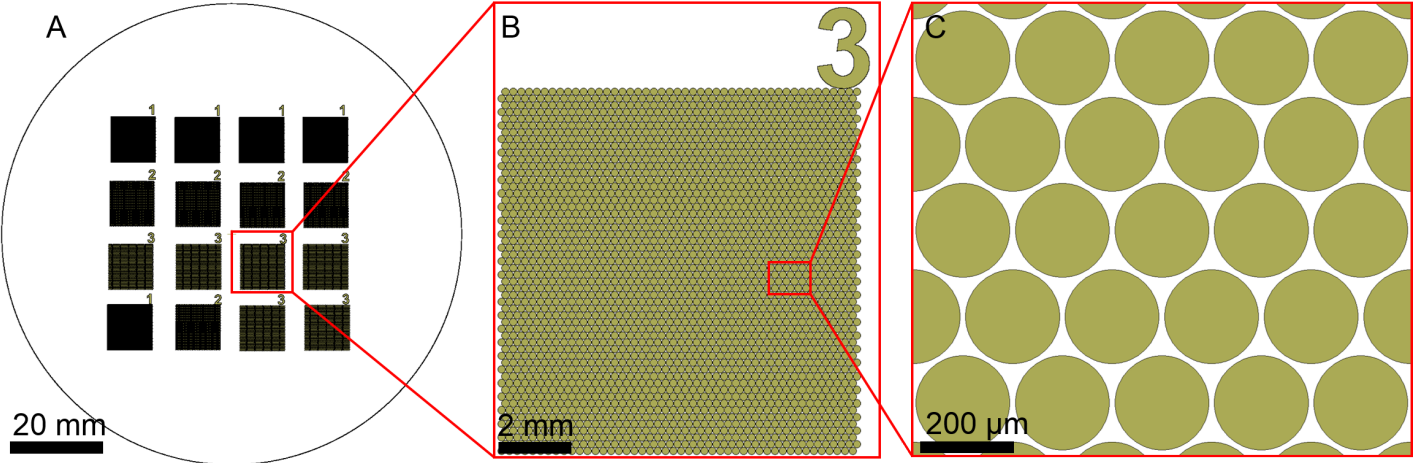
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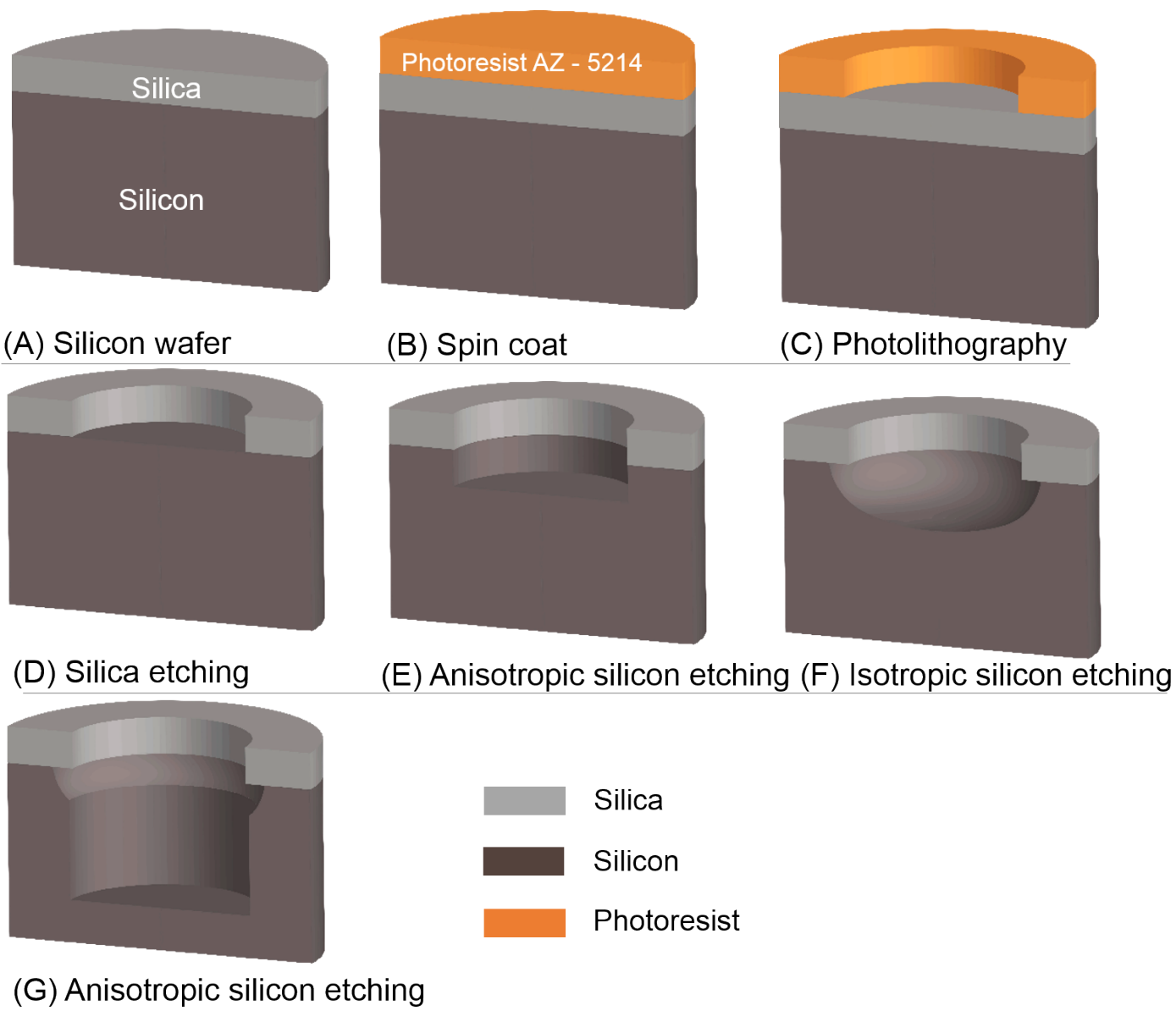
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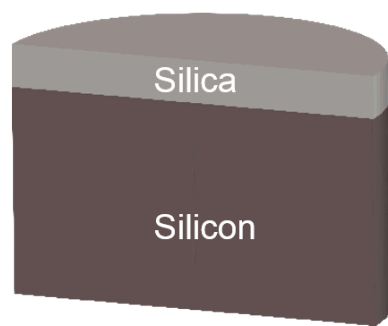
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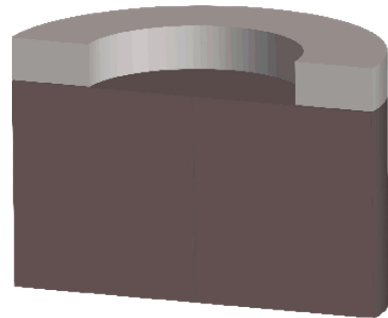
(A) Silicon wafer



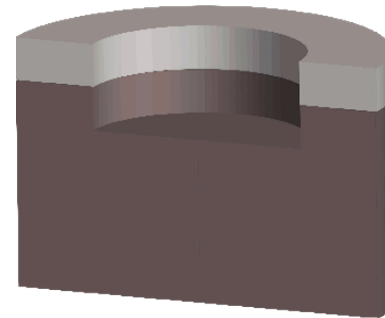
(B) Spin coat



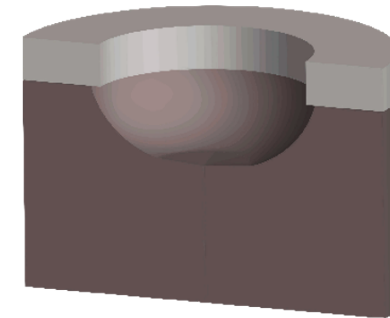
(C) Photolithography



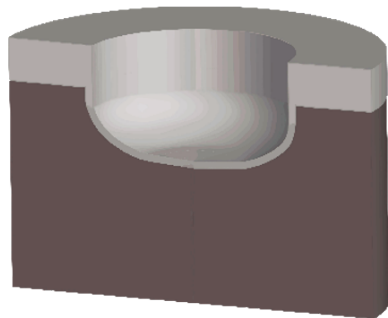
(D) Silica etching



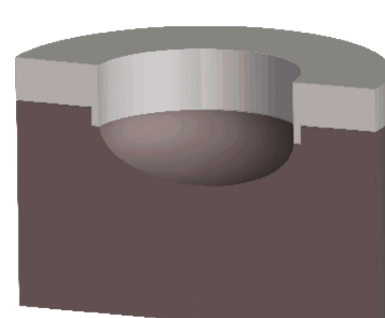
(E) Anisotropic silicon etching



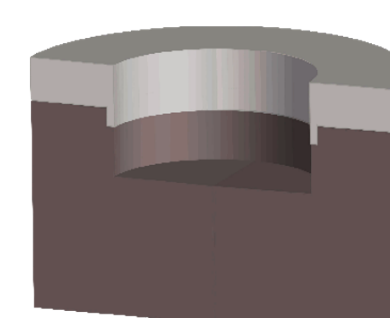
(F) Isotropic silicon etching



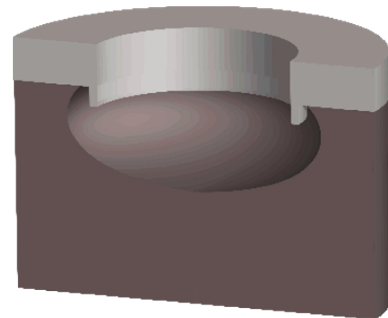
(G) Thermal oxide growth



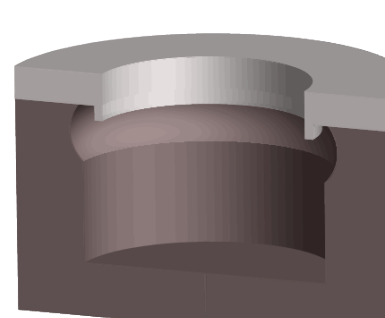
(H) Silica etching



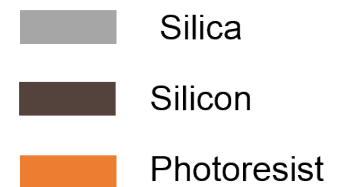
(I) Anisotropic silicon etching

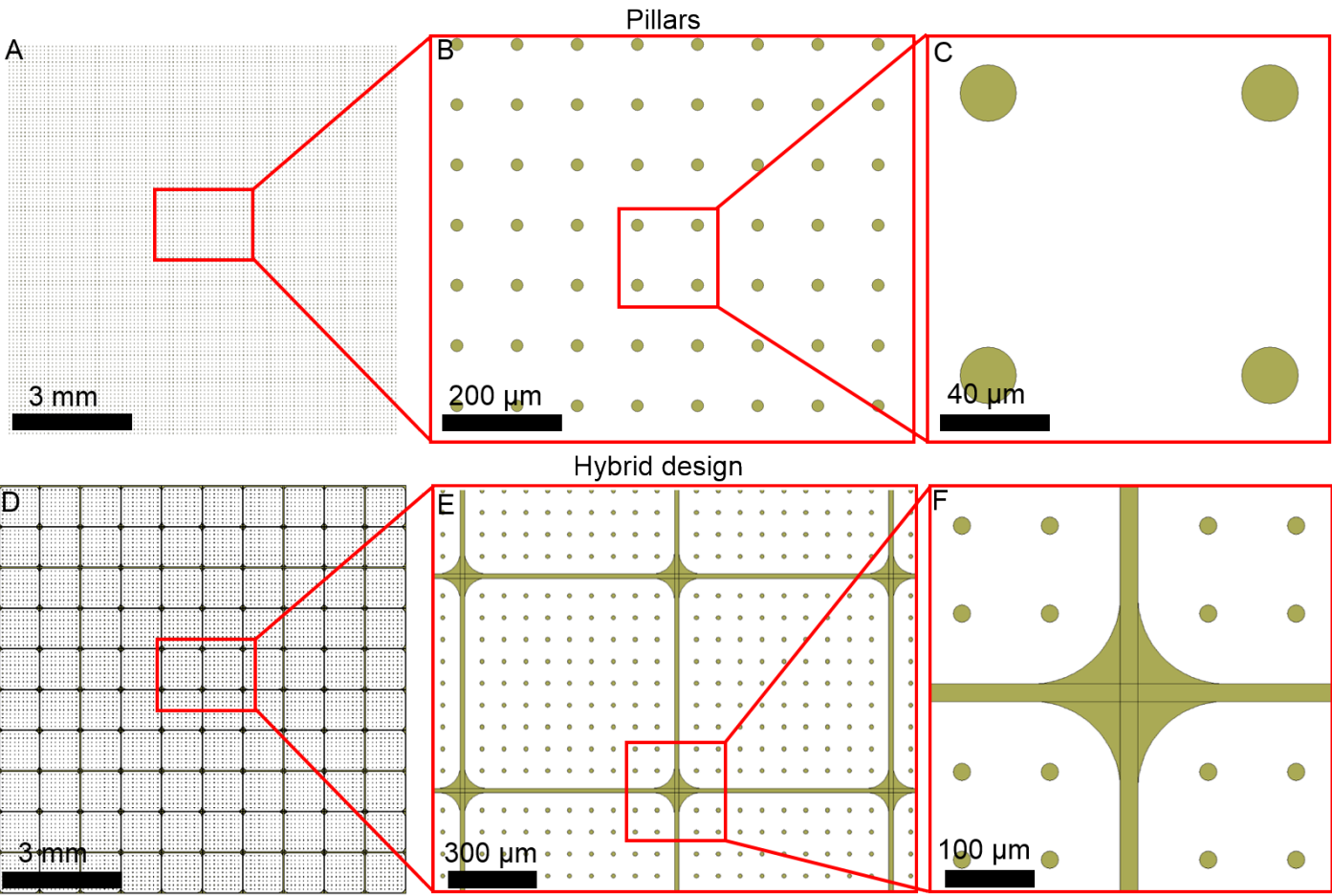


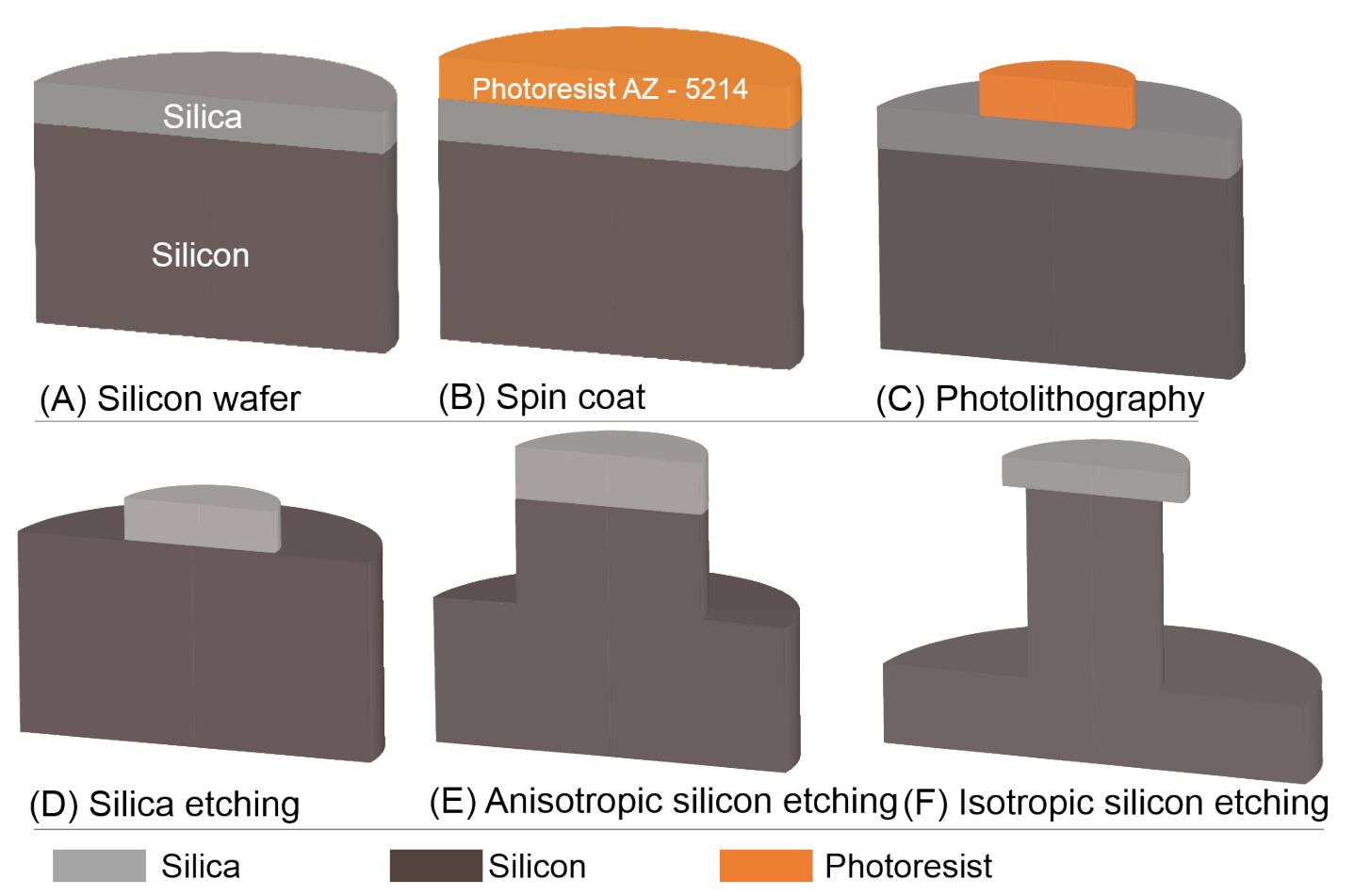
(J) Isotropic silicon etching

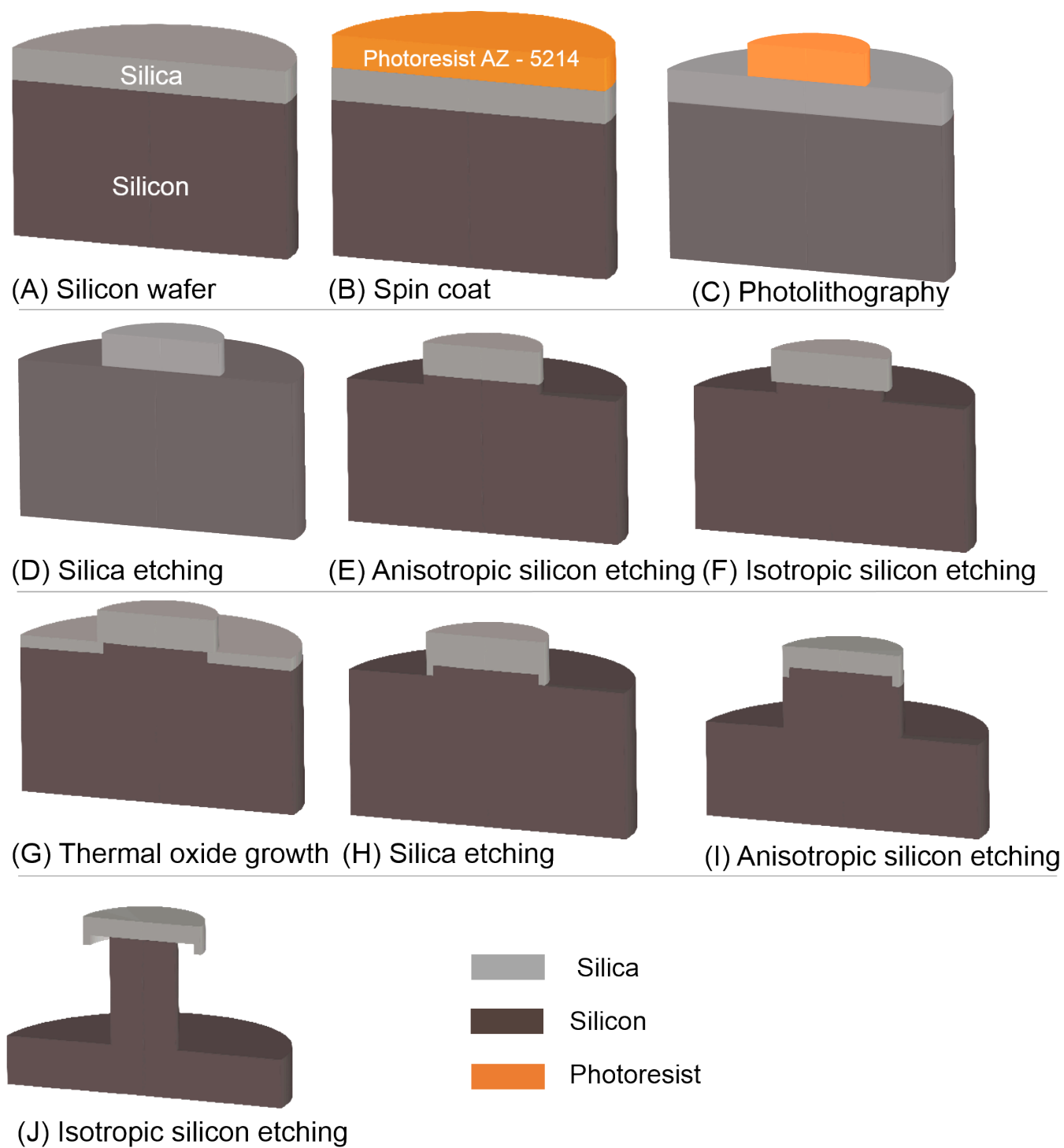


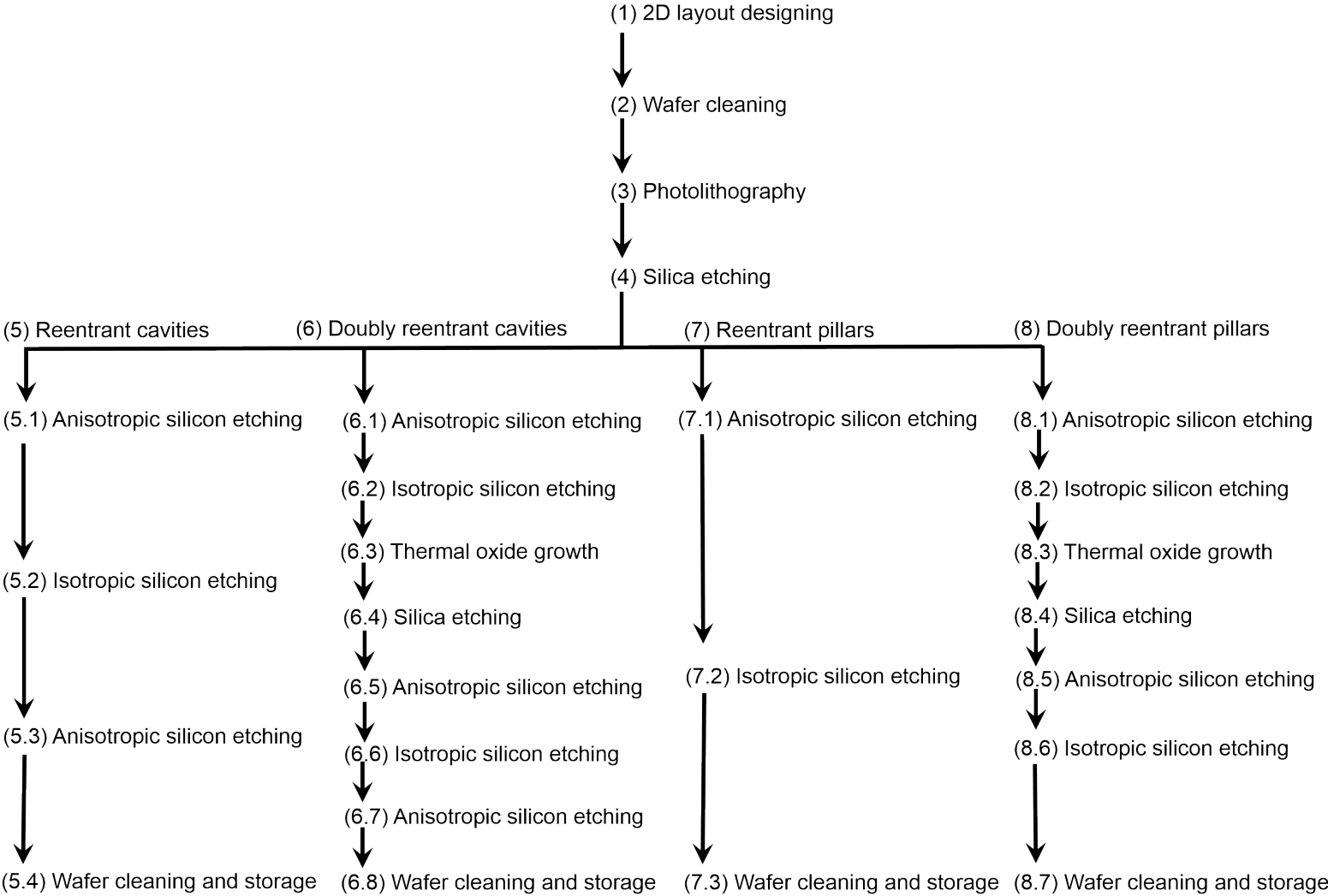
(K) Anisotropic silicon etching



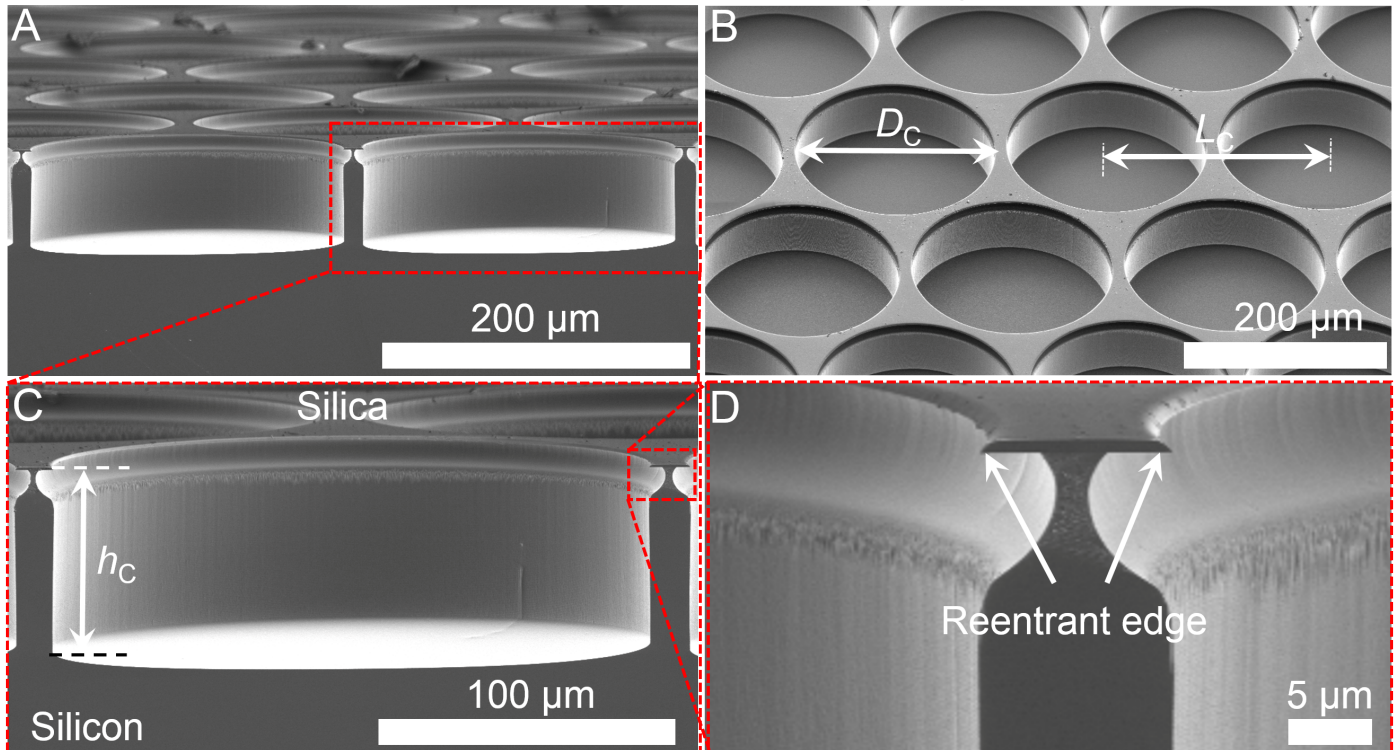




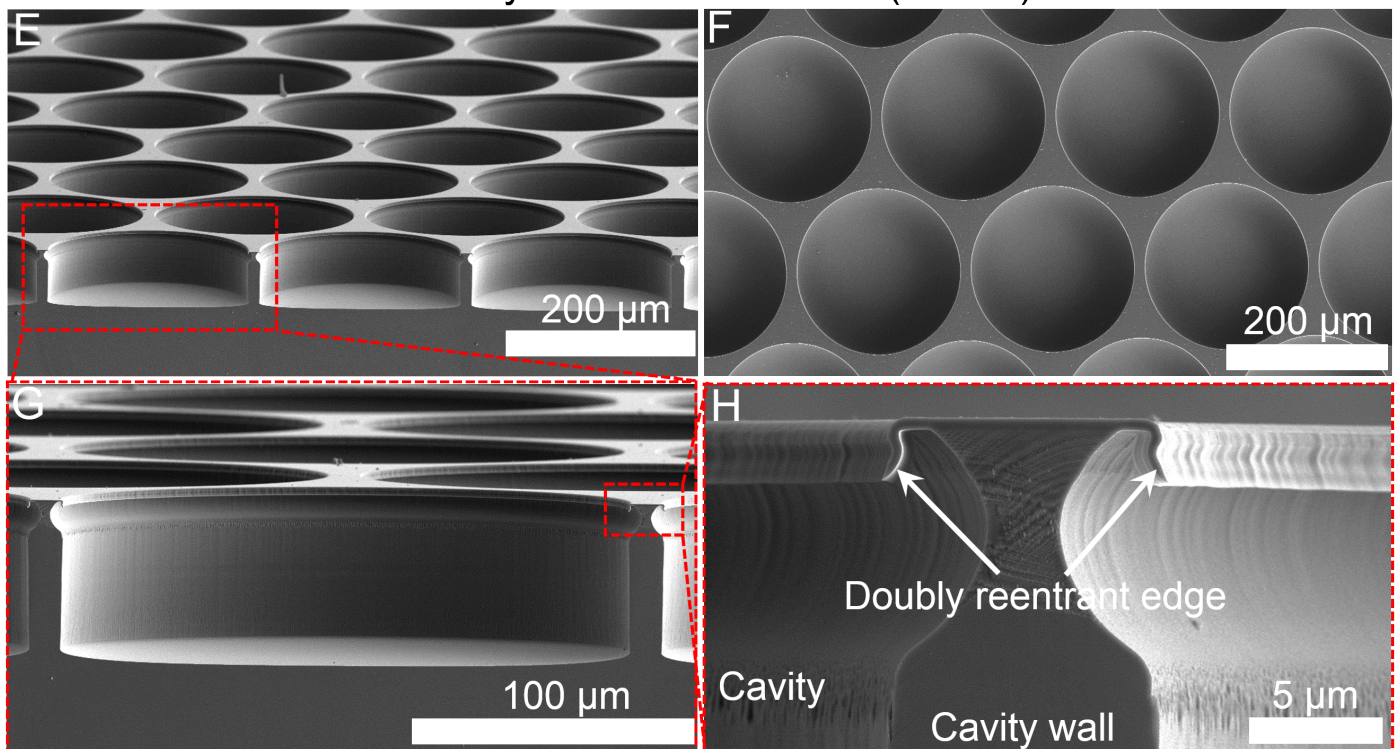




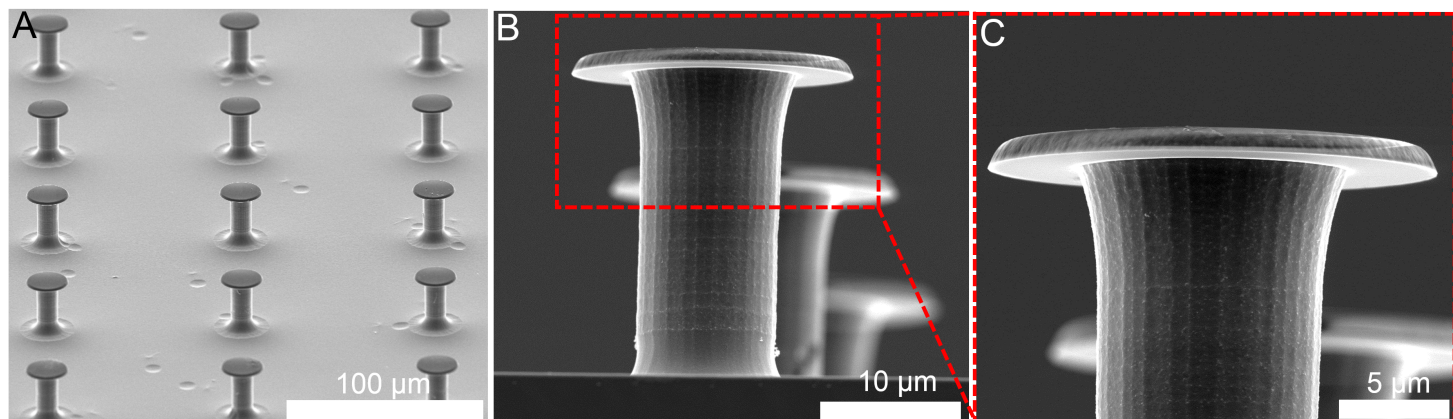
Reentrant cavities (RCs)



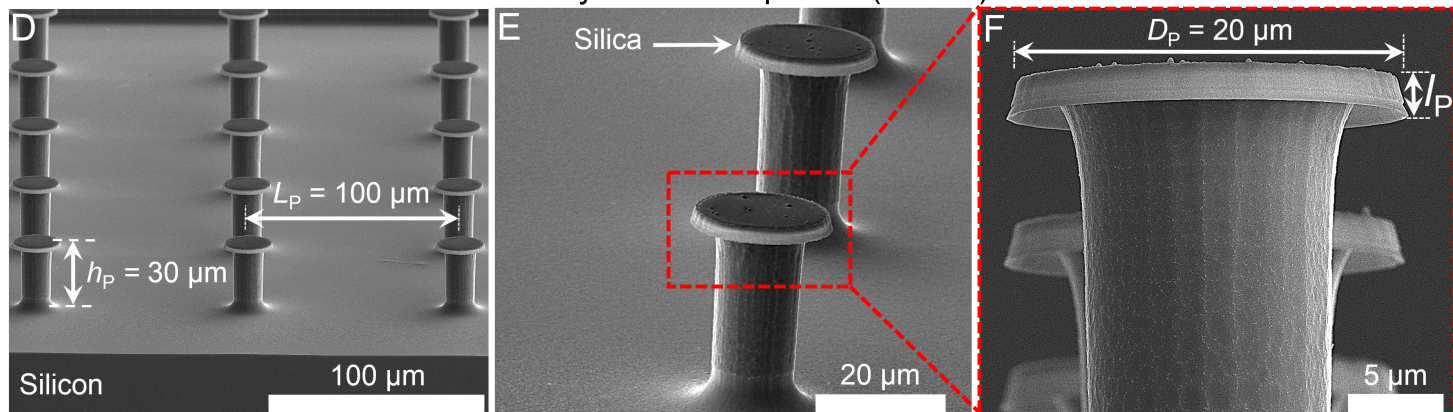
Doubly reentrant cavities (DRCs)



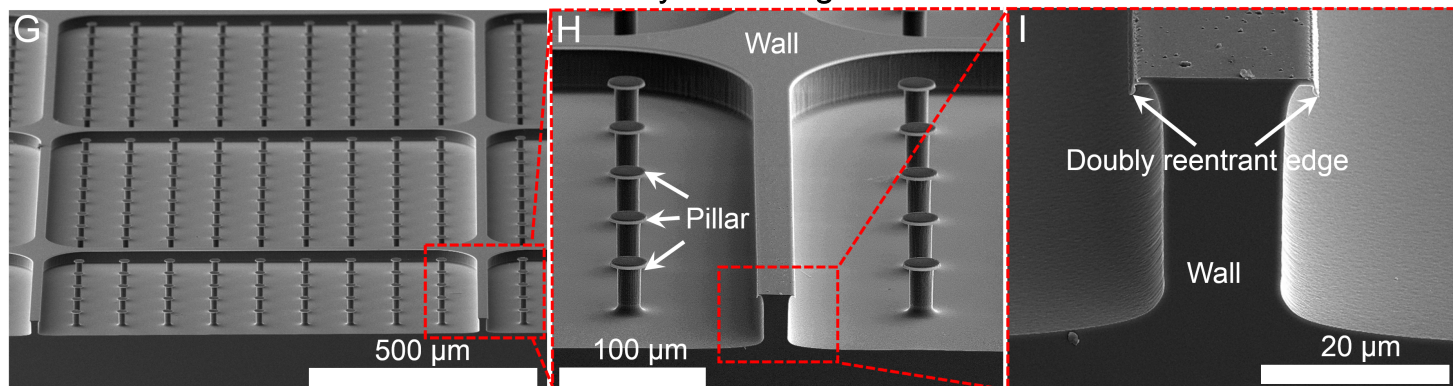
Reentrant pillars (RPs)

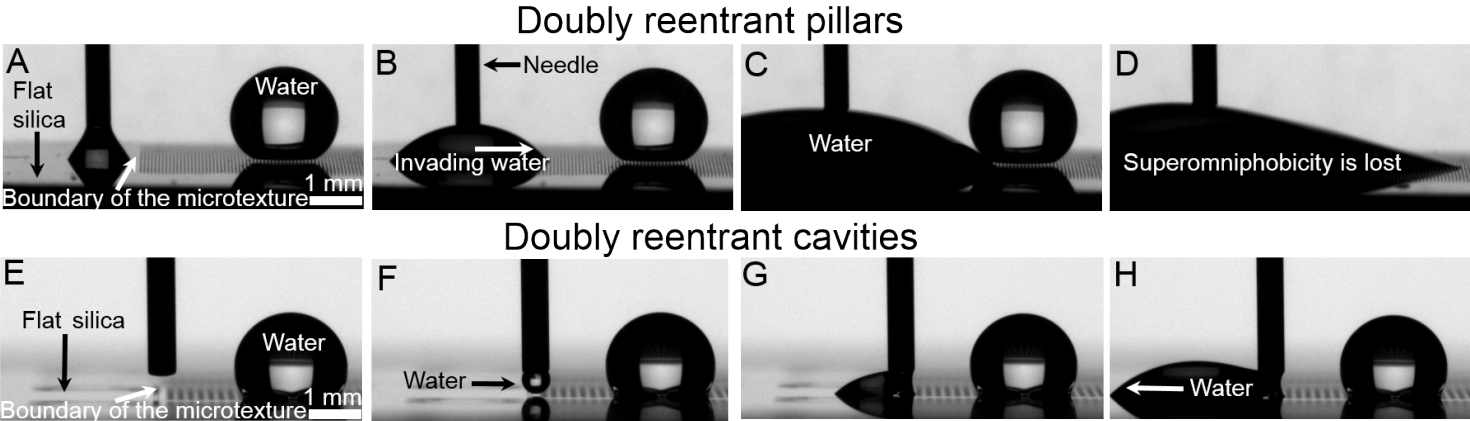


Doubly reentrant pillars (DRPs)

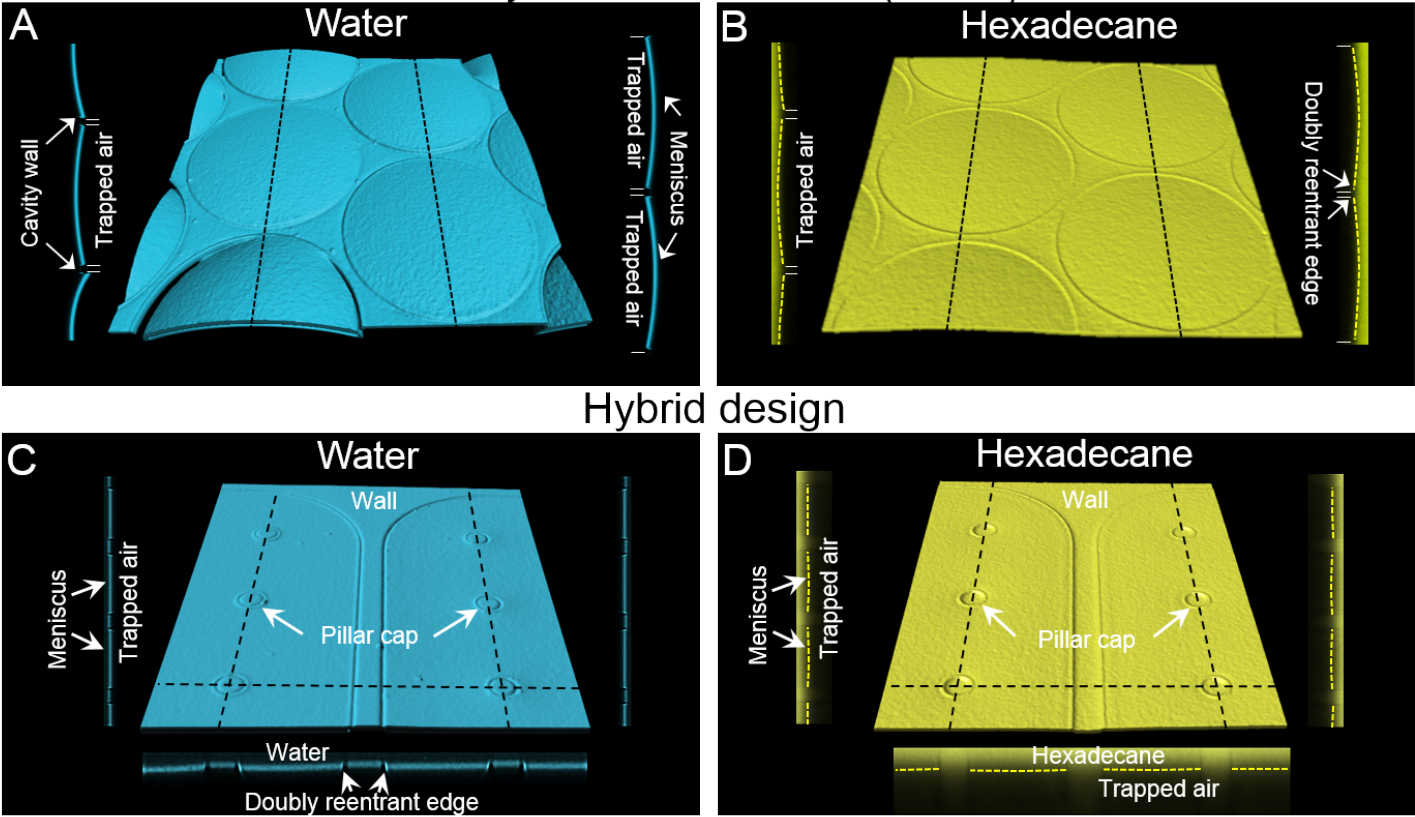


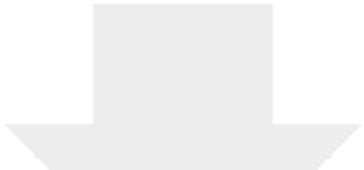
Hybrid design



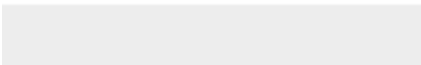



Doubly reentrant cavities (DRCs)





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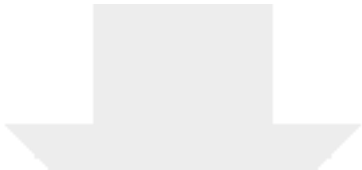
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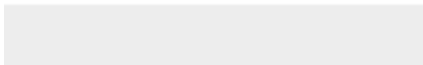
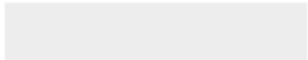


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Stage 1: Dehydration and purging oxygen from chamber		
Step	Process sequence	Time (min)
1	Vacuum (10 Torr)	1
2	Nitrogen (760 Torr)	3
3	Vacuum (10 Torr)	1
4	Nitrogen (760 Torr)	3
5	Vacuum (10 Torr)	1
6	Nitrogen (760 Torr)	3
Stage 2: Priming		
	Process sequence	Time (min)
7	Vacuum (1 Torr)	2
8	HMDS (6 Torr)	5
Stage 3: Purging Prime Exhaust		
	Process sequence	Time (min)
9	Vacuum	1
10	Nitrogen	2
11	Vacuum	2
Stage 4: Return to Atmosphere (Backfill)		
	Process sequence	Time (min)
12	Nitrogen	3

Step	Speed (rpm)	Ramp (rpm/s)	Time (s)
1	800	1000	3
2	1500	1500	3
3	3000	3000	30

RF power, (W)	ICP power, (W)	Etching pressure, (mTorr)	C ₄ F ₈ flow (sccm)	O ₂ flow (sccm)	Temperature, (°C)
100	1500	10	40	5	10

RF power, (W)	ICP power, (W)	Etching pressure, (mTorr)	SF ₆ flow, (sccm)	Temperature, (°C)
20	1800	35	110	15

Step	RF power, (W)	ICP power, (W)	Etching pressure, (mTorr)	SF ₆ flow, (sccm)	C ₄ F ₈ flow, (sccm)	Tempera ture, (°C)	Deposition/ Etching time, (s)
Passivation layer	5	1300	30	5	100	15	5
Etching	30	1300	30	100	5	15	7

Surfaces	Criterion: Contact angles in air			Criterion: Immersion	
		Water	Hexadecane	Water	Hexadecane
DRPs	θ_{T}	153°±1°	153° ± 1°	Instantaneous penetration	Instantaneous penetration
	θ_{A}	161°±2°	159° ± 1°		
	θ_{R}	139°±1°	132° ± 1°		
Assessment:	Superomniphobic			Not omniphobic – in fact, <i>omniphilic</i>	
DRCs	θ_{T}	124° ± 2°	115° ± 3°	Trapped air (omniphobic)	Trapped air (omniphobic)
	θ_{A}	139° ± 3°	134° ± 5°		
	θ_{R}	0°	0°		
Assessment:	Omniphobic			Omniphobic	
Hybrids	θ_{T}	153°± 2°	153° ± 2°	Trapped air (omniphobic)	Trapped air (omniphobic)
	θ_{A}	161°± 2°	159° ± 2°		
	θ_{R}	0°	0°		
Assessment:	Omniphobic			Omniphobic	

Name of Material/ Equipment	Company	Catalog Number
AZ-5214 E photoresist	Merck	DEAA070796-0W59
AZ-726 MIF developer	Merck	10055824960
Confocal microscopy	Zeiss	Zeiss LSM710
Deep ICP-RIE	Oxford Instruments	Plasmalab system100
Direct writer	Heidelberg Instruments	μPG501
Drop shape analyzer	KRUSS	DSA100
Hexadecane	Alfa Aesar	544-76-3
Highspeed imaging camera	Phantom vision research	v1212
HMDS vapor prime	Yield Engineering systems	
Hot plate	Cost effective equipments	Model 1300
Hydrogen peroxide 30%	Sigma Aldrich	7722-84-1
Imaris software	Bitplane	Version 8
Nile Red	Sigma Aldrich	7385-67-3
Nitrogen gas	KAUST lab supply	
Petri dish	VWR	HECH41042036
Reactive-Ion Etching (RIE)	Oxford Instruments	Plasmalab system100
Reflectometer	Nanometrics	Nanospec 6100
Rhodamine B (Acros)	Fisher scientific	81-88-9
SEM stub	Electron Microscopy Sciences	75923-19
SEM-Quanta 3D	FEI	Quanta 3D FEG Dual Beam
Silicon wafer	Silicon Valley Microelectronics	
Spin coater	Headway Research,Inc	PWM32
Spin rinse dryer	MicroProcess technology	Avenger Ultra -Pure 6
Sulfuric acid 96%	Technic	764-93-9
Tanner EDA L-Edit software	Tanner EDA, Inc.	version15
Thermal oxide growth	Tystar furnace	
Tweezers	Excelta	490-SA-PI
Vacuum oven	Thermo Scientific	13-258-13

Water	Milli-Q	Advantage A10
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Comments/Description
Photoresist, flammable liquid
To develop photoresist
Upright confocal microscope to visualize liquid meniscus shape
Silicon etching tool
Direct-writing system
To measure contact angle
Test liquid
To image droplet bouncing
To prepare piranha solution
Post process confocal microscopy images
Fluorescent dye for hexadecane
To dry the wafer
Silica etching tool
To check remaining oxide layer thickness
Fluorescent dye for water
Single side polished, 4" diameter, 500 μm thickness, 2.4 μm thick oxide layer
Dry the wafers after piranha clean
To prepare piranha solution
Layout design
To grow thermal oxide in patterned silicon wafer
Wafer tweezer

Test liquid

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Author(s):	Sankara Arunachalam, Eddy M. Domingues, Ratul Das, Jamilya Nauruzbayeva, Ulrich Buttner, Ahad Syed and Himanshu Mishra

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Supplementary Information

Rendering SiO₂/Si surfaces omniphobic by carving gas-entrapping microtextures comprising reentrant and doubly reentrant cavities or pillars

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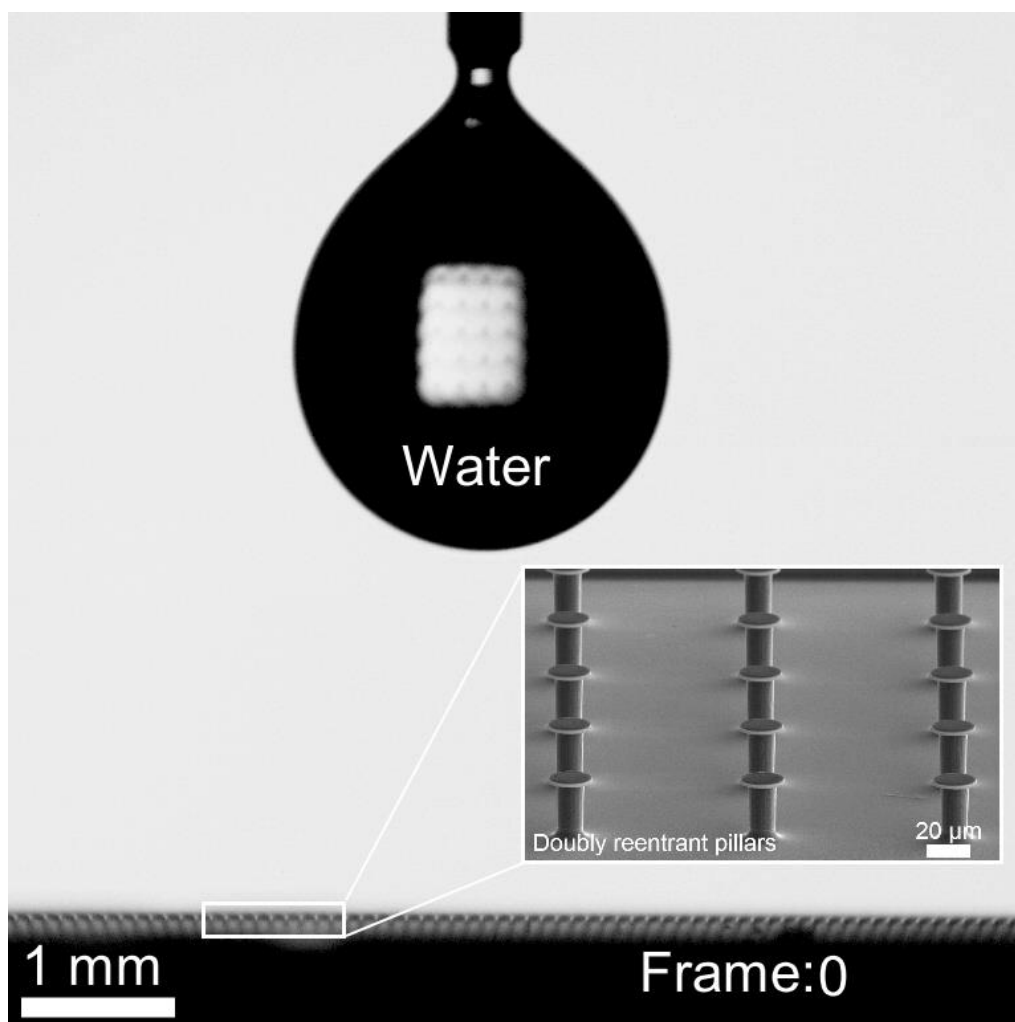
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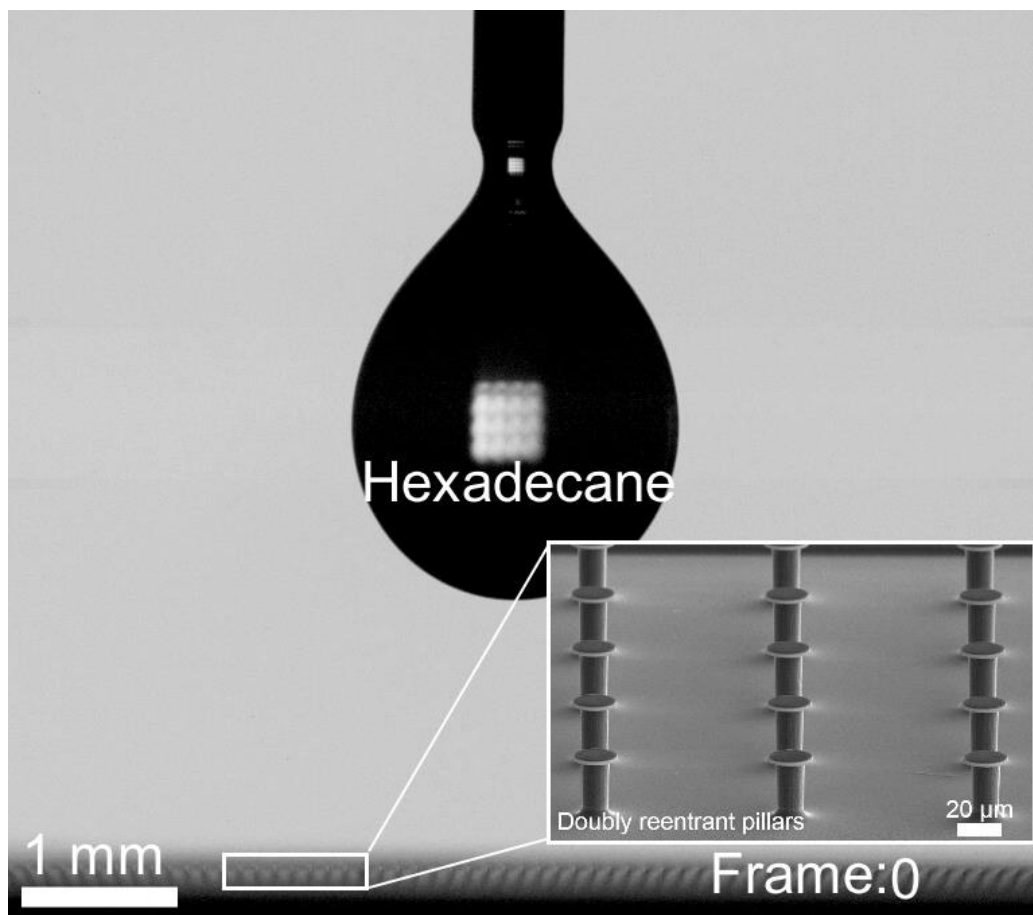
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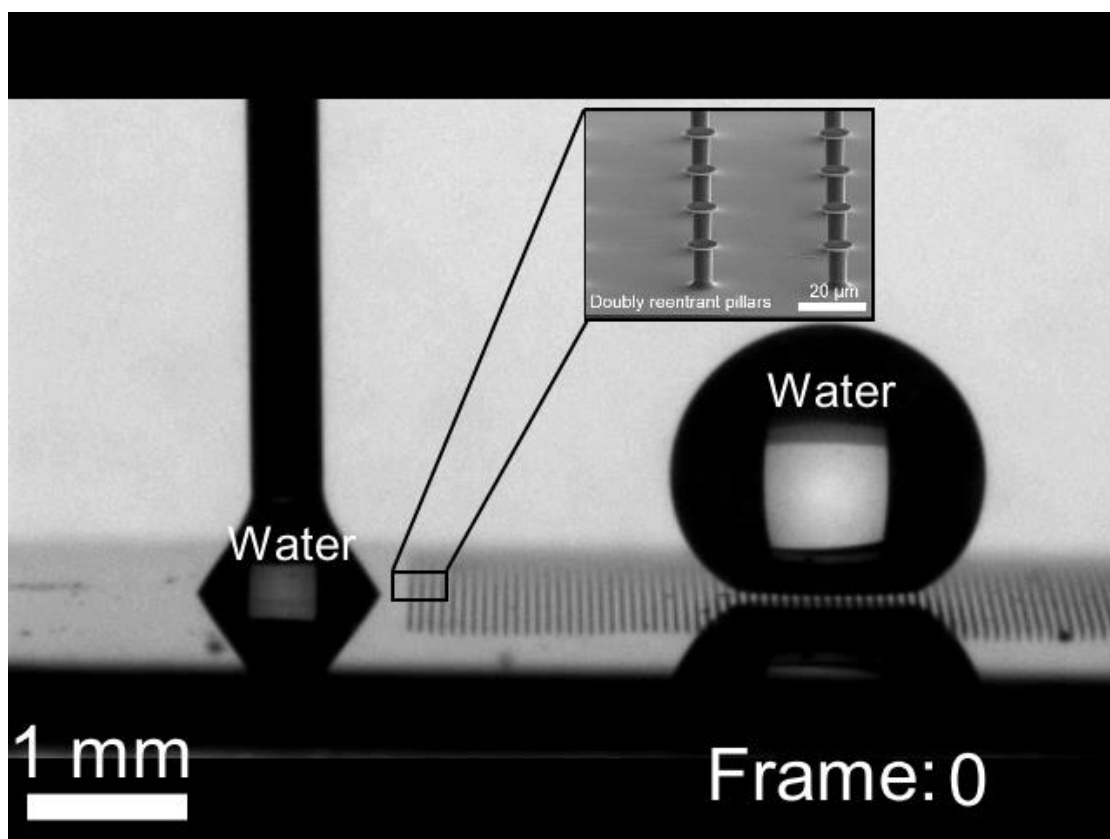
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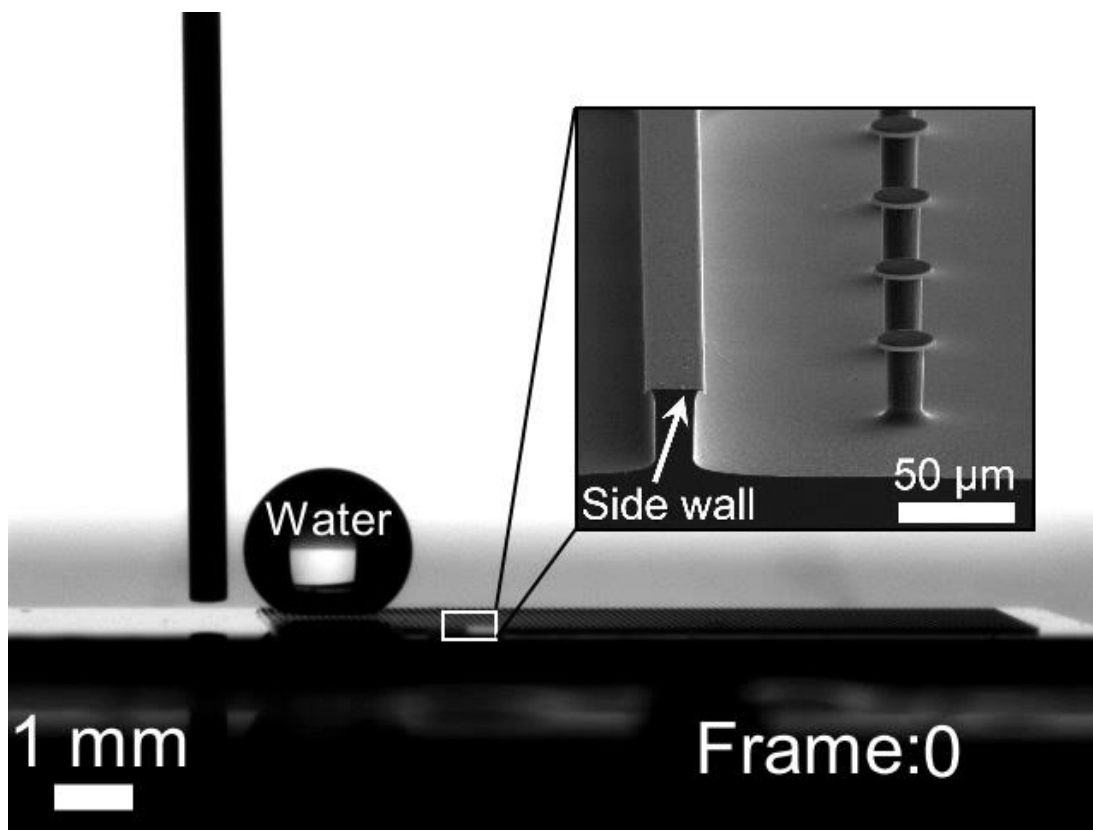
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Movie S4. Image sequence (200 fps) water drop advancing next to hybrid microtexture. Presence of doubly reentrant boundary wall prevents liquid invasion into the microtexture, which makes the surface omniphobic under immersion also. This movie was reprinted from ref 35. Copyright (2019), with permission from Elsevier.